

February 2001 Revised March 2002

74LCXH162373

Low Voltage 16-Bit Transparent Latch with Bushold and 26 Ω Series Resistor Outputs

General Description

The LCXH162373 contains sixteen non-inverting latches with 3-STATE outputs and is intended for bus oriented applications. The device is byte controlled. The flip-flops appear transparent to the data when the Latch Enable (LE) is HIGH. When LE is LOW, the data that meets the setup time is latched. Data appears on the bus when the Output Enable $(\overline{\text{OE}})$ is LOW. When $\overline{\text{OE}}$ is HIGH, the outputs are in a high impedance state.

The LCXH162373 is designed for low voltage (2.5V or 3.3V) V_{CC} applications with capability of interfacing to a 5V signal environment. The 26Ω series resistor helps reduce output overshoot and undershoot.

The LCXH162373 is fabricated with an advanced CMOS technology to achieve high speed operation while maintaining CMOS low power dissipation.

The LCXH162373 data inputs include active bushold circuitry, eliminating the need for external pull-up resistors to hold unused or floating data inputs at a valid logic level.

Features

- 5V tolerant control inputs and outputs
- 2.3V-3.6V V_{CC} specifications provided
- \blacksquare Equivalent 26 Ω series resistors on outputs
- Bushold on inputs eliminates the need for external pull-up/pull-down resistors
- \blacksquare 6.2 ns t_{PD} max (V_{CC} = 3.3V), 20 μ A I_{CC} max
- Power down high impedance inputs and outputs
- ± 12 mA output drive ($V_{CC} = 3.0V$)
- Implements patented noise/EMI reduction circuitry
- Latch-up performance exceeds 500 mA
- ESD performance:

Human body model > 2000V

Machine model > 200V

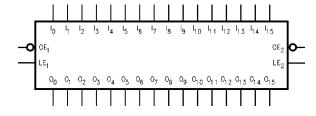
Also packaged in plastic Fine-Pitch Ball Grid Array (FBGA) (Preliminary)

Ordering Code:

Order Number	Package Number	Package Description
74LCXH162373GX (Note 1)	BGA54A (Preliminary)	54-Ball Fine-Pitch Ball Grid Array (FBGA), JEDEC MO-205, 5.5mm Wide [TAPE and REEL]
74LCXH162373MEA	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide [RAIL]
74LCXH162373MEX	MS48A	48-Lead Small Shrink Outline Package (SSOP), JEDEC MO-118, 0.300" Wide [TAPE and REEL]
74LCXH162373MTD	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide [RAIL]
74LCXH162373MTX	MTD48	48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide [TAPE and REEL]

Note 1: BGA package available in Tape and Reel only.

Logic Symbol

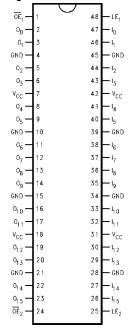


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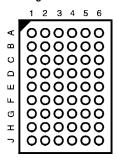
DS500445

Connection Diagrams

Pin Assignment for SSOP and TSSOP



Pin Assignment for FBGA



(Top Thru View)

Pin Descriptions

Pin Names	Description
OE _n	Output Enable Input (Active LOW)
LE _n	Latch Enable Input
I ₀ –I ₁₅	Inputs (Bushold)
O ₀ -O ₁₅ NC	Outputs (Bushold)
NC	No Connect

FBGA Pin Assignments

	1	2	3	4	5	6
Α	O ₀	NC	OE ₁	LE ₁	NC	I ₀
В	02	O ₁	NC	NC	I ₁	l ₂
С	O ₄	O ₃	V _{CC}	V _{CC}	I ₃	I_4
D	O ₆	O ₅	GND	GND	l ₅	I ₆
E	O ₈	O ₇	GND	GND	I ₇	I ₈
F	O ₁₀	O ₉	GND	GND	l ₉	I ₁₀
G	O ₁₂	O ₁₁	V _{CC}	V _{CC}	I ₁₁	I ₁₂
Н	O ₁₄	O ₁₃	NC	NC	I ₁₃	I ₁₄
J	O ₁₅	NC	OE ₂	LE ₂	NC	I ₁₅

Truth Tables

	Inputs		
LE ₁	OE ₁	I ₀ –I ₇	O ₀ -O ₇
Х	Н	Х	Z
Н	L	L	L
Н	L	Н	Н
L	L	Χ	O ₀

	Inputs		Outputs
LE ₂	OE ₂	I ₈ -I ₁₅	O ₈ -O ₁₅
Х	Н	Х	Z
Н	L	L	L
Н	L	Н	Н
L	L	X	O ₀

H = HIGH Voltage Level

L = LOW Voltage Level

X = Immaterial Z = High Impedance

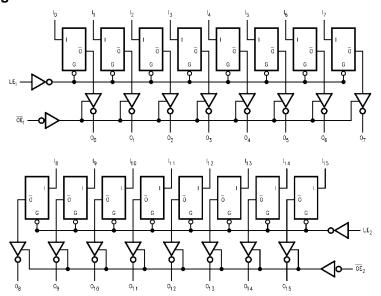
O₀ = Previous O₀ before HIGH-to-LOW transition of Latch Enable

Functional Description

The LCXH162373 contains sixteen D-type latches with 3-STATE standard outputs. The device is byte controlled with each byte functioning identically, but independent of the other. Control pins can be shorted together to obtain full 16-bit operation. The following description applies to each byte. When the Latch Enable (LE_n) input is HIGH, data on the I_n enters the latches. In this condition the latches are transparent, i.e. a latch output will change state each time

its I input changes. When LE $_n$ is LOW, the latches store information that was present on the I inputs a setup time preceding the HIGH-to-LOW transition of LE $_n$. The 3-STATE standard outputs are controlled by the Output Enable $(\overline{\text{OE}}_n)$ input. When $\overline{\text{OE}}_n$ is LOW, the standard outputs are in the 2-state mode. When $\overline{\text{OE}}_n$ is HIGH, the standard outputs are in the high impedance mode but this does not interfere with entering new data into the latches.

Logic Diagrams



Please note that this diagram is provided only for the understanding of logic operations and should not be used to estimate propagation delays.

Ιo

 I_{CC}

 I_{GND}

 T_{STG}

Absolute Maximum Ratings(Note 2) Symbol Parameter Value Conditions Units -0.5 to +7.0 Supply Voltage V_{CC} V_{I} DC Input Voltage -0.5 to $V_{CC} + 0.5$ ٧ $\overline{\text{OE}}_{\text{n}}$, LE_{n} -0.5V to 7.0V DC Output Voltage ٧o -0.5 to +7.0 Output in 3-STATE -0.5 to $V_{CC} + 0.5$ Output in HIGH or LOW State (Note 3) DC Input Diode Current -50 $V_I < GND$ mΑ I_{IK}

-50

+50

±50

±100

±100

-65 to +150

V_O < GND

 $V_{O} > V_{CC}$

 $\mathsf{m}\mathsf{A}$

mΑ

mΑ

Recommended Operating Conditions (Note 4)

Symbol	Parameter		Min	Max	Units
V _{CC}	Supply Voltage	Operating	2.0	3.6	V
		Data Retention	1.5	3.6	V
VI	Input Voltage		0	V _{CC}	V
Vo	Output Voltage	HIGH or LOW State	0	V _{CC}	V
		3-STATE	0	5.5	V
I _{OH} /I _{OL}	Output Current	$V_{CC} = 3.0V - 3.6V$		±12	
		$V_{CC} = 2.7V - 3.0V$ $V_{CC} = 2.3V - 2.7V$		±8	mA
		$V_{CC} = 2.3V - 2.7V$		±4	
T _A	Free-Air Operating Temperature		-40	85	°C
Δt/ΔV	Input Edge Rate, V _{IN} = 0.8V–2.0V, V _{CC} = 3.0V		0	10	ns/V

Note 2: The Absolute Maximum Ratings are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the Absolute Maximum Ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

DC Output Diode Current

Storage Temperature

DC Output Source/Sink Current

DC Supply Current per Supply Pin

DC Ground Current per Ground Pin

Note 4: Floating or unused control inputs must be HIGH or LOW.

DC Electrical Characteristics

Symbol	Parameter	Conditions	V _{CC}	$T_A = -40^{\circ}C$ to $+85^{\circ}C$		Units
•		Conditions	(V)	Min	Max	Units
V _{IH}	HIGH Level Input Voltage		2.3 – 2.7	1.7		V
			2.7 – 3.6	2.0		V
V _{IL}	LOW Level Input Voltage		2.3 – 2.7		0.7	V
			2.7 – 3.6		0.8	V
V _{OH}	HIGH Level Output Voltage	$I_{OH} = -100 \mu A$	2.3 – 3.6	V _{CC} - 0.2		
		$I_{OH} = -4 \text{ mA}$	2.3	1.8		
		$I_{OH} = -4 \text{ mA}$	2.7	2.2		V
		$I_{OH} = -6 \text{ mA}$	3.0	2.4		
		$I_{OH} = -8 \text{ mA}$	2.7	2.0		
		$I_{OH} = -12 \text{ mA}$	3.0	2.0		
V _{OL}	LOW Level Output Voltage	I _{OL} = 100 μA	2.3 – 3.6		0.2	
		I _{OL} = 4 mA	2.3		0.6	
		I _{OL} = 4 mA	2.7		0.4	V
		I _{OL} = 6 mA	3.0		0.55	V
		I _{OL} = 8 mA	2.7		0.6	
		I _{OL} = 12 mA	3.0		0.8	
I _I	Input Leakage Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		±5.0	μΑ

Note 3: I_O Absolute Maximum Rating must be observed.

DC Electrical Characteristics (Continued)

Symbol	Parameter	Conditions	V _{CC}	$T_A = -40^{\circ}C \text{ to } +85^{\circ}C$		Units
		Conditions	(V)	Min	Max	Offics
I _{I(HOLD)}	Bushold Input Minimum	V _{IN} = 0.7V	2.3	45		
	Drive Hold Current	$V_{IN} = 1.7V$	2.3	-45		μА
		$V_{IN} = 0.8V$	3.0	75		μΛ
		$V_{IN} = 2.0V$	3.0	-75		
I _{I(OD)}	Bushold Input Over-Drive	(Note 6)	2.7	300		
Cur	Current to Change State	(Note 7)	2.1	-300		μА
		(Note 6)	3.6	450		μΛ
		(Note 7)	3.0	-450		
I _{OZ}	3-STATE Output Leakage	0 ≤ V _O ≤ 5.5V	2.3 – 3.6		±5.0	μА
		$V_I = V_{IH}$ or V_{IL}	2.5 - 5.0		±3.0	μΛ
I _{OFF}	Power-Off Leakage Current	$V_O = V_{CC}$	0		10	μΑ
I _{CC}	Quiescent Supply Current	$V_I = V_{CC}$ or GND	2.3 – 3.6		20	^
		$3.6V \le V_O \le 5.5V \text{ (Note 5)}$	2.3 – 3.6		±20	μΑ
ΔI_{CC}	Increase in I _{CC} per Input	$V_{IH} = V_{CC} - 0.6V$	2.3 – 3.6		500	μΑ

Note 5: Outputs disabled or 3-STATE only.

AC Electrical Characteristics

	Parameter		$T_A = -40$ °C to $+85$ °C, $R_L = 500\Omega$					
Symbol		$V_{CC} = 3.3V \pm 0.3V$ $C_L = 50 \text{ pF}$		V _{CC} = 2.7V C _L = 50 pF		$V_{CC} = 2.5V \pm 0.2V$ $C_L = 30 \text{ pF}$		Units
	Farameter							
		Min	Max	Min	Max	Min	Max	
t _{PHL}	Propagation Delay	1.5	6.2	1.5	6.7	1.5	7.4	ns
t _{PLH}	I _n to O _n	1.5	6.2	1.5	6.7	1.5	7.4	115
t _{PHL}	Propagation Delay	1.5	6.3	1.5	7.2	1.5	7.6	ns
t _{PLH}	LE to O _n	1.5	6.3	1.5	7.2	1.5	7.6	115
t _{PZL}	Output Enable Time	1.5	6.9	1.5	7.3	1.5	9.0	ns
t_{PZH}		1.5	6.9	1.5	7.3	1.5	9.0	115
t _{PLZ}	Output Disable Time	1.5	6.0	1.5	6.3	1.5	7.2	ns
t_{PHZ}		1.5	6.0	1.5	6.3	1.5	7.2	115
t _S	Setup Time, In to LE	2.5		2.5		3.0		ns
t _H	Hold Time, I _n to LE	1.5		1.5		2.0		ns
t _W	LE Pulse Width	3.0		3.0		3.5		ns
toshl	Output to Output Skew (Note 8)		1.0					ns
toslh			1.0					ns

Note 8: Skew is defined as the absolute value of the difference between the actual propagation delay for any two separate outputs of the same device. The specification applies to any outputs switching in the same direction, either HIGH-to-LOW (t_{OSHL}) or LOW-to-HIGH (t_{OSLH}). Parameter guaranteed by design.

Note 6: An external driver must source at least the specified current to switch from LOW-to-HIGH.

 $[\]textbf{Note 7:} \ \textbf{An external driver must sink at least the specified current to switch from HIGH-to-LOW}.$

Dynamic Switching Characteristics

Symbol	Parameter	Conditions	V _{CC} (V)	T _A = 25°C	Units
V _{OLP}	Quiet Output Dynamic Peak V _{OL}	C _L = 50 pF, V _{IH} = 3.3V, V _{IL} = 0V	3.3	0.35	\ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \ \
		$C_L = 30 \text{ pF, } V_{IH} = 2.5 \text{V, } V_{IL} = 0 \text{V}$	2.5	0.25	V
V _{OLV}	Quiet Output Dynamic Valley V _{OL}	$C_L = 50 \text{ pF}, V_{IH} = 3.3 \text{V}, V_{IL} = 0 \text{V}$	3.3	-0.35	\/
		$C_L = 30 \text{ pF}, V_{IH} = 2.5 \text{V}, V_{IL} = 0 \text{V}$	2.5	-0.25	V

Capacitance

Symbol	Parameter	Conditions	Typical	Units
C _{IN}	Input Capacitance	$V_{CC} = Open, V_I = 0V \text{ or } V_{CC}$	7	pF
C _{OUT}	Output Capacitance	$V_{CC} = 3.3V$, $V_I = 0V$ or V_{CC}	8	pF
C _{PD}	Power Dissipation Capacitance	$V_{CC} = 3.3V$, $V_{I} = 0V$ or V_{CC} , $f = 10$ MHz	20	pF

AC LOADING and WAVEFORMS Generic for LCX Family

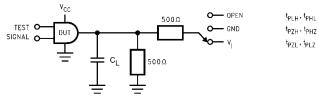
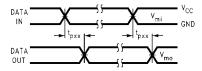
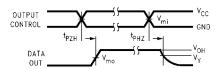


FIGURE 1. AC Test Circuit (C_L includes probe and jig capacitance)

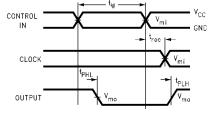
Test	Switch
t _{PLH} , t _{PHL}	Open
t _{PZL} , t _{PLZ}	6V at V_{CC} = 3.3 \pm 0.3V, and 2.7V V_{CC} x 2 at V_{CC} = 2.5 \pm 0.2V
t _{PZH} , t _{PHZ}	GND



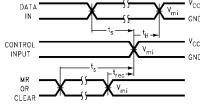
Waveform for Inverting and Non-Inverting Functions



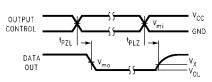
3-STATE Output High Enable and Disable Times for Logic



Propagation Delay. Pulse Width and t_{rec} Waveforms



Setup Time, Hold Time and Recovery Time for Logic



3-STATE Output Low Enable and Disable Times for Logic

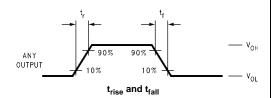
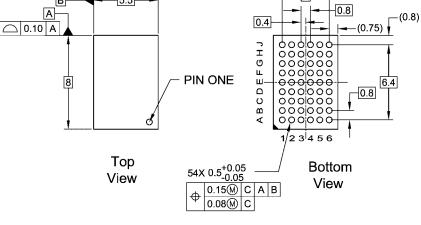
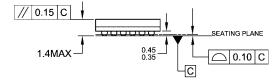


FIGURE 2. Waveforms (Input Characteristics; f = 1 MHz, $t_r = t_f = 3$ ns)

Symbol	V _{cc}		
	$3.3V \pm 0.3V$	2.7V	2.5V ± 0.2V
V_{mi}	1.5V	1.5V	V _{CC} /2
V_{mo}	1.5V	1.5V	V _{CC} /2
V _x	V _{OL} + 0.3V	V _{OL} + 0.3V	V _{OL} + 0.15V
V _y	V _{OH} – 0.3V	V _{OH} – 0.3V	V _{OH} – 0.15V

Physical Dimensions inches (millimeters) unless otherwise noted ○ 0.10 B В 5.5 Α 0.10 A





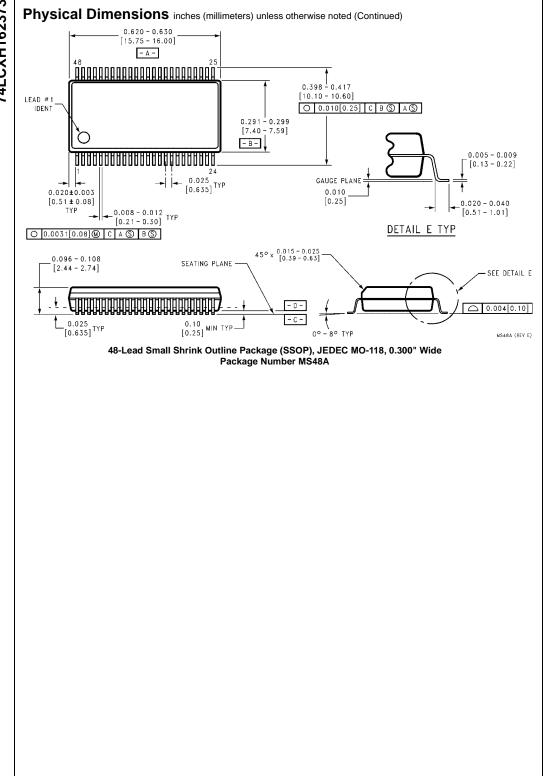
NOTES:

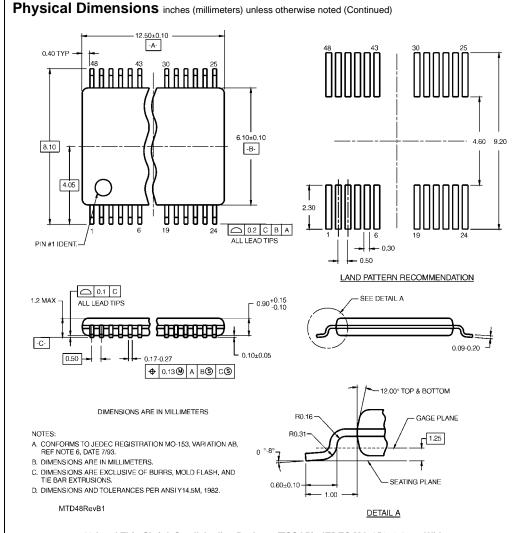
- A. THIS PACKAGE CONFORMS TO JEDEC M0-205
- **B. ALL DIMENSIONS IN MILLIMETERS**
- C. LAND PATTERN RECOMMENDATION: NSMD (Non Solder Mask Defined)
 .35MM DIA PADS WITH A SOLDERMASK OPENING OF .45MM CONCENTRIC TO PADS
 D. DRAWING CONFORMS TO ASME Y14.5M-1994

BGA54ArevD

54-Ball Fine-Pitch Ball Grid Array (FBGA), JEDEC MO-205, 5.5mm Wide Package Number BGA54A Preliminary







48-Lead Thin Shrink Small Outline Package (TSSOP), JEDEC MO-153, 6.1mm Wide Package Number MTD48

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